

Name

PID

**UNIVERSITY OF CALIFORNIA, SAN DIEGO**

Electrical and Computer Engineering Department

ECE 65 – Fall 2020

*Components and Circuits lab*

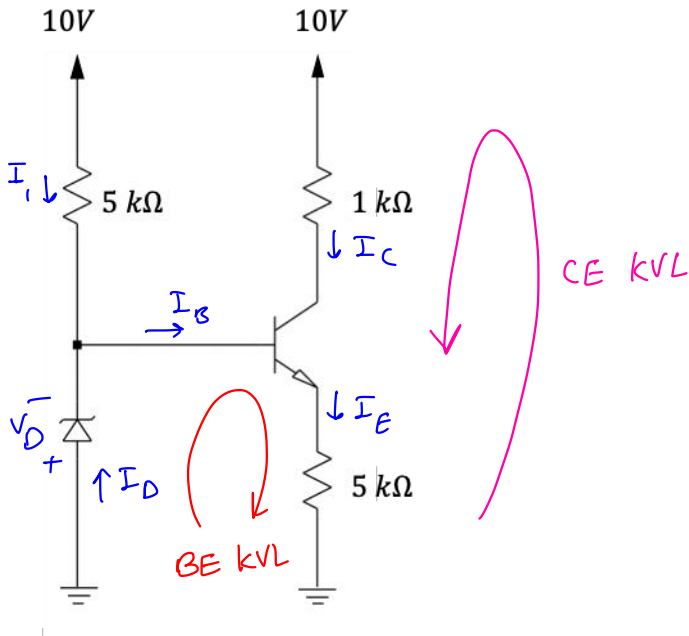
Final Exam **Solutions**

You should submit your handwritten solutions in a PDF format to Gradescope by Wednesday, 12/16, at 11:00 am (Pacific Time).

**Problem 1.** (5 points)

Find the node voltages and the currents in all branches in the following circuit.

Assume  $V_{D0} = 0.7\text{ V}$ ,  $V_{sat} = 0.2\text{ V}$ ,  $V_Z = 6.2\text{ V}$ ,  $\beta = 100$



**Show your work.**

Assume the Zener diode is in the Zener region and the BJT is ON and in active region.

$$V_D = -V_Z = -6.2\text{ V}, \quad I_D \leq 0, \quad V_{BE} = V_{D0} = 0.7\text{ V}$$

$$I_C = \beta I_B = \frac{\beta}{1+\beta} I_E, \quad V_{CE} \geq V_{D0}$$

**Problem 1.** (5 points)

KCL at the base:  $I_B = I_1 + I_D$

Ohm's law:  $I_1 = \frac{10V - V_Z}{5k\Omega} = \frac{10 - 6.2V}{5k\Omega} = 0.76 \text{ mA}$

BE KVL:  $V_D + V_{BE} + 5k\Omega \times I_E = 0 \rightarrow -6.2V + 0.7 + 5k\Omega \times I_E = 0$   
 $\rightarrow I_E = 1.1 \text{ mA}$

$I_C = \frac{100}{101} \times 1.1 \text{ mA} \approx 1.09 \text{ mA}$

CE KVL:  $10V = 1k\Omega \times I_C + 5k\Omega \times I_E + V_{CE}$

$\rightarrow V_{CE} = 10 - 1.09 - 5.5 = 3.41 \text{ V} \geq V_{D_0}$

$I_B = \frac{I_C}{100} \approx 0.0109 \text{ mA} \approx 11 \mu\text{A}$

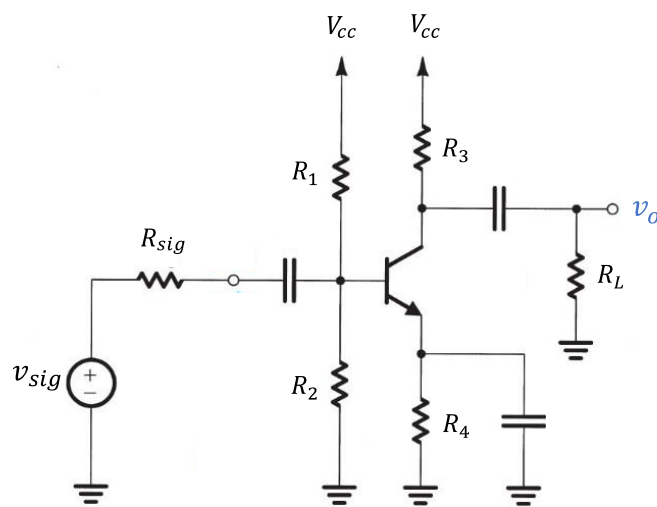
KCL at the base:  $I_D = I_B - I_1$   
 $= 0.0109 \text{ mA} - 0.76 \text{ mA} \approx -0.749 \text{ mA} \leq 0$

$V_{CE} \geq V_{D_0}$  and  $I_D \leq 0$ , the assumption was correct.

**Problem 2.** (10 points)

Assume

- $V_{D0} = 0.7\text{ V}$ ,  $V_{sat} = 0.2\text{ V}$ , and  $\beta = 100$ ,  $V_T = 26\text{ mV}$
- The power supply available is  $15\text{ V}$ .
- The output resistance of the signal source is  $1\text{ k}\Omega$  ( $R_{sig} = 1\text{ k}\Omega$ ) and the load resistance is  $1\text{ k}\Omega$ .
- Capacitors are short in the signal circuit.
- Ignore the early effect in bias and signal circuit calculations.



Design the above amplifier circuit such that

- The collector current is  $2\text{ mA}$ .
- The Thevenin equivalent resistance at the base is about one tenth of  $R_E$ .
- The absolute value of the total gain of the amplifier ( $A = \frac{v_o}{v_{sig}}$ ) is at least  $10\text{ V/V}$ .

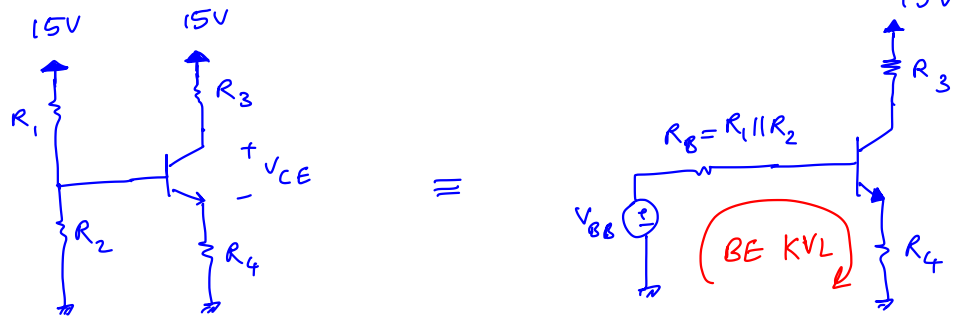
In your answers, make sure to include

- All the resistor values.
- All the DC node voltages.
- The total gain of the amplifier.
- Choose a sinusoidal signal with  $f = 1\text{ kHz}$  (choose the peak amplitude of the signal yourself), and sketch both  $v_{sig}$  and  $v_o$ .

**Show your work. This is a design problem, so there are multiple answers for this problem.**

**Problem 2.** (5 points)

Bias circuit:



$$R_B = 0.1 R_E, \quad I_C = 2 \text{ mA}, \quad \beta = 100$$

$$\text{BJT is in active mode} \Rightarrow I_E = \frac{1+\beta}{\beta} I_C = 2.02 \text{ mA}$$

There are multiple ways to design this circuit.

$$\text{I chose } R_E = 4 \text{ k}\Omega \text{ and } R_B = 0.4 \text{ k}\Omega.$$

$$V_E = R_E \times I_E = 4 \text{ k}\Omega \times 2.02 \text{ mA} = 8.08 \text{ V}$$

$$\text{BE KVL: } V_{BB} = R_B I_B + V_{BE} + V_E = 0.4 \text{ k}\Omega \times \frac{2.02 \text{ mA}}{101} + 0.7 + 8.08$$

$$V_{BB} = 8.79 \text{ V}$$

$$R_B = \frac{R_1 R_2}{R_1 + R_2} = 0.4 \text{ k}\Omega, \quad \frac{R_2}{R_1 + R_2} \times 15 \text{ V} = V_{BB} = 8.79 \text{ V}$$

$$R_1 = 680 \Omega, \quad R_2 = 971 \Omega$$

**Problem 2.** (10 points)

$$A = \frac{v_o}{v_{sig}} = \frac{R_i}{R_i + R_{sig}} \times A_{v_o} \times \frac{R_L}{R_L + R_o}$$

$$R_i = R_B \parallel r_{\pi} \quad , \quad A_{v_o} = -g_m (R_C \parallel r_o) = -g_m R_C \quad , \quad R_o = R_C \parallel r_o = R_C$$

$$g_m = \frac{I_C}{V_T} = \frac{2 \text{ mA}}{26 \text{ mV}} = 76.9 \text{ (mA/V)}$$

$$r_{\pi} = \frac{\beta}{g_m} = 1.3 \text{ k}\Omega$$

$$R_i = 0.4 \text{ k}\Omega \parallel 1.3 \text{ k}\Omega = 0.31 \text{ k}\Omega$$

I chose  $A = -10 \text{ V/V}$

$$A = \frac{v_o}{v_{sig}} = \frac{0.31 \text{ k}\Omega}{0.31 \text{ k}\Omega + 1 \text{ k}\Omega} \times (-76.9 \text{ (mA/V)} R_C) \times \frac{1 \text{ k}\Omega}{1 \text{ k}\Omega + R_C} = -10 \text{ V/V}$$

→  $R_C = 1.18 \text{ k}\Omega$

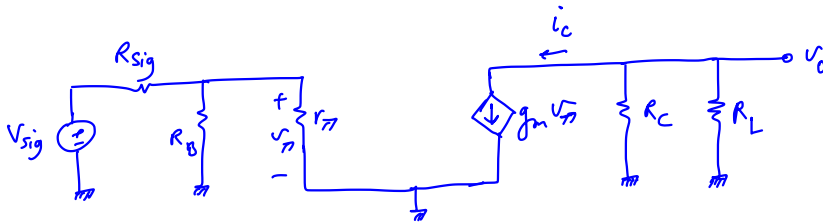
The bias node voltages:  $V_C = V_{CC} - R_C I_C = 15 \text{ V} - 1.18 \text{ k}\Omega \times 2 \text{ mA} = 12.64 \text{ V}$   
 $V_B = V_E + V_{BE} = 8.78 \text{ V}$

$V_C = 12.64 \text{ V}$  ,  $V_E = 8.08 \text{ V}$  ,  $V_B = 8.78 \text{ V}$

$V_{CE} = 4.56 \text{ V} > V_{D_0} \rightarrow \text{BJT is in active region}$

**Problem 2.** (10 points)

at DC,  $V_C = 12.64 \text{ V}$  and  $V_{CC} = 15 \text{ V}$



$$v_{\pi} = \frac{r_{\pi} \parallel R_B}{(r_{\pi} \parallel R_B) + R_{sig}} v_{sig} \rightarrow v_{\pi} = 0.24 v_{sig}$$

I chose  $\hat{v}_{sig} = 10 \text{ mV} \rightarrow \hat{v}_{\pi} = 2.4 \text{ mV} < 5 \text{ mV}$

$$v_{sig} = 10 \sin(\omega t) \text{ (mV)}, \quad \omega = 2\pi \times 1 \text{ kHz}$$

$$v_o = -10 v_{sig} \rightarrow |\hat{v}_o| = 100 \text{ mV} \rightarrow v_o = -100 \sin(\omega t) \text{ (mV)}, \quad \omega = 2\pi \times 1 \text{ kHz}$$

$v_o = v_c$ , the signal part of the collector node voltage and  $v_o$  are the same.

$$v_C = V_C + v_c = 12.64 \text{ V} - 0.1 \text{ (V)} \sin(\omega t)$$

$$v_E = V_E + v_e = V_E + 0 = 8.08$$

$$v_{CE} = v_C - v_E = 4.56 \text{ (V)} - 0.1 \text{ (V)} \sin(\omega t) > 0.7 \text{ at all times}$$

